

HT201XX One Lamp/LED Flash Driver

Features

- CMOS Metal-Gate Process Technology
- Operating voltage: 1.2V~4.5V
- Low standby current: 1µA Typ. at 3V
- Built-in oscillator (Fosc: 32KHz)
- ON/OFF control function for the HT2013H, HT2013M, HT2013L
- 1/8 duty cycle output
- Directly driving an LED
- Minimum external components
- TO-92 package (only for the HT2012H, HT2014M, HT2014L)

- Flash rate options:
 - HT2013H \rightarrow about 4Hz
 - HT2012H \rightarrow about 4Hz (No ON/OFF control function)
 - HT2013M \rightarrow about 2Hz
 - HT2014M \rightarrow about 2Hz
 - (No ON/OFF control function)
 - HT2013L \rightarrow about 1Hz
 - HT2014L \rightarrow about 1Hz
 - (No ON/OFF control function)

General Description

The HT201XX series is a low cost, low power CMOS LSI chip designed for lamp and LED flash drivers. It can be operated without any external components, thus suitable for applications on flashing badges, gift cards, flashing earrings, and other products that require flashing lights.

Selection Table

Part No.	Flash Rate	ON/OFF Control		Package		
Fait NO.		Yes	No	TO-92	Dice	
HT2013H	4Hz	\checkmark			\checkmark	
HT2012H	4Hz		\checkmark	\checkmark	\checkmark	
HT2013M	2Hz	\checkmark			\checkmark	
HT2014M	2Hz		\checkmark	\checkmark	\checkmark	
HT2013L	1Hz	\checkmark			\checkmark	
HT2014L	1Hz			V	\checkmark	

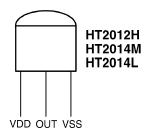
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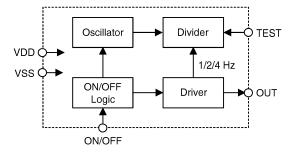


Unit: mil

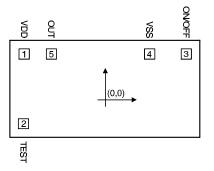
Pin Assignment



Block Diagram



Pad Coordinates



Pad No.	X	Y
1	-23.9	13.5
2	-24.13	-7.055
3	23.89	13.5
4	13.09	13.5
5	-15.89	13.5

Chip size: $60 \times 38 \text{ (mil)}^2$

*The IC substrate should be connected to VDD in PCB layout artwork.

Pad Description

Pad No.	Pad Name	I/O	Internal Connection	Description
1	VDD	—	—	Power supply (positive)
2	TEST	—	_	For IC test only
3	ON/OFF	Ι	CMOS Pull-High	Lamp/LED flash ON/OFF control pad
4	VSS	_		Power supply (ground)
5	OUT	0	NMOS Open Drain	Lamp/LED flash output

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Absolute Maximum Ratings

Supply Voltage	–0.3V to 5.5V
Input Voltage	$V_{SS}0.3V$ to $V_{DD}\mbox{+-}0.3V$

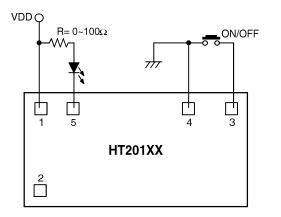
Storage Temperature–50°C to $125^\circ C$	
Operating Temperature20°C to 75°C	

Electrical Characteristics

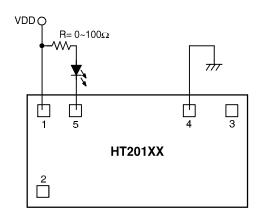
Symbol	Parameter	Test Condition		Min.	T	Man	Units
Symbol	Parameter	VDD	Condition	win.	Тур.	Max.	Units
V _{DD}	Operating Voltage	—	_	1.2	3	4.5	V
I _{STB}	Standby Current	3V	_	_	1	2	μΑ
I _{DD}	Operating Current	3V	No load	_	200	500	μΑ
Tee	OUT Pad Sink Current	1.5V	V _{OL} =0.15V	5	12	_	mA
Iol	OUT Fau Sink Current	3V	Vol=0.3V	10	30		mA
FOSC	System Frequency	3V		_	32K	—	Hz

Application Circuit

Chip form with ON/OFF control



Chip form without ON/OFF control



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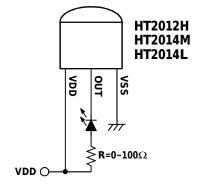
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Package form application



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